NSN 5961-01-018-1958

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View Online at https://aerobasegroup.com/nsn/5961-01-018-1958 **Inclosure Material:** Metal **Overall Length:** 5.6 millimeters **Overall Diameter:** 7.5 millimeters **Internal Configuration:** Junction contact **Mounting Method:** Terminal Features Provided: Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 3.75 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: